## IPP080N03L G Information



## Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.


## IPP080N03L G Specifications

| Manufacturer Part Number | IPP080N03L G |
| :--- | :--- |
| Manufacturer | Infineon Technologies |
| Category | Discrete Semiconductor Products |
|  | Transistors - FETs, MOSFETs - Single |
| Package | TO-220-3 |
| Series | OptiMOS? |
| FET Type | N-Channel |
| Technology | MOSFET (Metal Oxide) |
| Drain to Source Voltage (Vdss) | 30 V |
| Current - Continuous Drain (Id) @ $25^{\circ} \mathrm{C}$ | 50 A (Tc) |
| Drive Voltage (Max Rds On, Min Rds On) | $4.5 \mathrm{~V}, 10 \mathrm{~V}$ |
| Vgs(th) (Max) @ Id | 2.2 V @ 250~A |
| Gate Charge (Qg) (Max) @ Vgs | $18 \mathrm{nC} \mathrm{@} \mathrm{10V}$ |
| Input Capacitance (Ciss) (Max) @ Vds | 1900 pF @ 15V |
| Vgs (Max) | $\pm 20 \mathrm{~V}$ |
| FET Feature | - |
| Power Dissipation (Max) | 47 W (Tc) |
| Rds On (Max) @ Id, Vgs | 8 mOhm @ 30A, 10V |
| Operating Temperature | $-55^{\circ} \mathrm{C} \sim 175^{\circ} \mathrm{C}$ (TJ) |
| Mounting Type | Through Hole |
| Supplier Device Package | PG-TO220-3-1 |
| Package / Case | TO-220-3 |
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## IPP080N03L G Guarantees



## Quality Guarantees

We provide 90 days warranty. *
If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.

## IPP080N03L G Payment Methods



## IPP080N03L G Shipping Methods

If you have any question about IPP080N03L G, please do not hesitate to contact us!
Website: https://www.heisener.com
E-mail: salesdept@heisener.com

